University Institute of Technology (UIT)

Silver Wood Estate, H. P. University, Shimla-171005 (NAAC Accredited "A-Grade" University)



DEPARTMENT Of ELECTRONICS & COMMUNICATION ENGINEERING

Course Work Syllabus For

DOCTOR OF PHILOSOPHY

In

ELECTRONICS & COMMUNICATION ENGINEERING

Effective for the Batch 2021and onwards

Course of Study For Doctoral Program

DOCTOR OF PHILOSOPHY IN ELECTRONICS & COMMUNICATION ENGINEERING UIT, HIMACHAL PARDESH UNIVERSITY, SHIMLA

C.N.			т	т	Ъ		Semester End Marks	
S. No.	Course No.	Course Name	L	Т	Р	C	External	Internal
1.	PEC-2001	Advanced Nano scale Devices	3	1	0	4	100	50
2	PEC-2002	Materials for Nano Technology	3	1	0	4	100	50
3	PEC-2003	Space-Time Wireless Communication	3	1	0	4	100	50
4.	PEC-2004	Advanced Wireless Networks	3	1	0	4	100	50
5.	PEC -2005	Advanced Computer Networks and Protocols	3	1	0	4	100	50
6.	PEC -2006	Optoelectronics Devices and Circuits	3	1	0	4	100	50
7.	PEC-2007	Artificial Intelligence	3	1	0	4	100	50
8.	PEC-2008	Design for IOT	3	1	0	4	100	50
9.	PEC-2009	Computational Electro magnetic	3	1	0	4	100	50
10.	PEC-2010	Machine and Deep Learning	3	1	0	4	100	50
11.	PEC-2011	Flexible and Printable Electronics Technology	3	1	0	4	100	50
12.	PEC-2012	Advanced Antenna Theory and Design	3	1	0	4	100	50
13.	PEC-2013	Nano photonics	3	1	0	4	100	50

Legend:

- L Number of lecture hours per week.
- **T** Number of tutorial hours per week.
- **P** Number of practical hours per week.
- C- Total no. of credit

DETAILED SYLLABUS

DOCTOR OF PHILOSOPHY IN ELECTRONICS & COMMUNICATION ENGINEERING UIT, HIMACHAL PARDESH UNIVERSITY, SHIMLA

Name of th	e Course	Advanced Nano scale Devices				
Course Co	de	PEC-2001 Credits-4 L-3, T-1, P-0				
Total Lectu	ures	52 (1 Hr Each) (L=	39, T=13 for each seme	ster)		
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	sional tests 50%, ttendance 10%)	Max Marks: 50		
		Instruc	tions			
For Paper	Setters:					
The questic will consist entire sylla course. Sec and each qu	on paper will const t of a single quest bus and will car tion A, B, C & I tuestion will carry	sist of five Sections A stion with 10-20 subpa- ry 20% of the total n o will have two questi- 20% of the total marks	, B, C, D & E. Section E arts of short answer type, narks of the semester en- ons from the respective so of the semester end exam	will be compulsory, it which will cover the d examination for the ections of the syllabus ination for the course.		
For Candid	lates:					
Candidates	are required to	attempt five question	is in all selecting one qu	uestion from each of		
the sections	A, B, C & D	of the question pap	er and all the subparts	of the questions in		
Section E. A	A non- programm	nable calculatoris all	owed to use in examination	tions.		
 Course on ★ To nanot ★ To br desig 	introduce stude technologies, for ridge the existin n.	ents to the emergents to the emergents to the emergent of the second circuits. It is good to be the second circuits of the second circuit	ging design paradign electronic device resea	ns in various new rch and nano systems		
Section	Course Content					
Section-A	Challenges In Nano Science & Nano Technology: Quantum mechanical, Physical and Biological aspects of Nano science & Technology, Nano defects, Nano layers and Nano structuring,Growth and Fabrication of Nano structures, Electron transport in papo structures					
	Nano Structur	ed Electronic Devic	es: Nano tunneling devi	ces, Self organization		
Section-B	Section-B phenomena at nano crystal surfaces, Engineering of complex nanostructures, Quantum dot nanostructures for single electron devices, Carbon nano tubes and carbon electronics, Quantum electronic devices (QEDs).					
Section-C	<i>Organic Electronics:</i> Complex integrated systems and information processing at nano scale, Limits of integrated systems and nano devices.					
Section-D	<i>Concept Of Hetero Structure Devices: Oxide hetero structures, photo voltaic, sensors, actuators, quantum dot hetero structure lasers etc. Nano-MEMS, Introduction to quantum computation and soft computing.</i>					
Course Outcomes: CO1: Obtain the knowledge on advanced Nano scale devices.						

CO2: Understand the operation and design Fin FET based circuits.

DOCTOR OF PHILOSOPHY IN ELECTRONICS & COMMUNICATION ENGINEERING UIT, HIMACHAL PARDESH UNIVERSITY, SHIMLA

CO3: Design reliable circuits using nano wire arrays and CNT interconnects.CO4: Understand the design aspects of application specific Nano scale ICs.

Text Books:

- 1. Nano science and Nanotechnology in Engineering, V. K. Vardanet. al., World Scientific, 2010.
- 2. Introduction to Nanotechnology &Nano electronics: Materials, Devices and Measurement Techniques, W. R. Fahrner, Springer, 2005.
- Introduction to Nano electronics : Science, Technology, Engineering & Applications, V. V. Mitin, V. A. Kochelap, M. A. Satroscio, Cambridge University Press, 2008.
- 4. Nano electronics and Nano systems, K. Goser, P. Glosekotter, J. Dienstuhi, Springer, 2005.
- 5. Nano structures, V. A. Shchukin, N. N. Ledentsov, D. Bimberg, Springer, 2007.
- 6. Semiconductor LASERS I & II: Fundamentals, E. Kapon, Academic Press (Indian edition), 2006.

- 1. Optical Materials, John H. Simmons and Kelly S. Potter, Academic Press (Indian edition), 2006.
- 2. Electronic Properties of Materials, Rolf E. Hummel, Springer (3rd edition).
- 3. Energy Storage, R. A. Huggins, Springer, 2010.
- 4. Fundamentals of Photovoltaic Modules and their Applications, G. N. Tiwari, S. Dubey & Julian C. R. Hunt, RSC Energy Series, 2009

Name of th	ne Course	Materials for Nanotechnology				
Course Co	de	PEC-2002	Credits-4	L-3, T-1, P-0		
Total Lect	Lectures 52 (1 Hr Each) (L=39, T=13 for each seme			ster)		
Semester H Examinati	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment:	(based on ses , Ouiz/Seminar 10%, At	sional tests 50%,	Max Marks: 50		
	8	Instruc	tions			
For Paper	Setters:					
The question will consist entire syllat course. Section and each que	on paper will co t of a single qu bus and will ca tion A, B, C & uestion will carry	nsist of five Sections A, estion with 10-20 subpa urry 20% of the total n D will have two question 20% of the total marks	, B, C, D & E. Section E arts of short answer type, narks of the semester endons from the respective se of the semester end exam	will be compulsory, it which will cover the d examination for the ections of the syllabus ination for the course.		
For Candi	dates:					
Candidates the sections Section E. A	are required to s A, B, C & I A non- program	attempt five question O of the question pap mable calculatoris all	is in all selecting one queer and all the subparts owed to use in examination	uestion from each of of the questions in tions.		
 The g and na The c mecha 	oal of this cou ano-technology course provide anics.	rse is to provide an in s basics of nano-ma	nsight into the fundament	ntals of Nano science nanics and statistical		
Section		Cor	urse Content			
Section-A	Advantages Of Nano Electrical And Electronic Devices: Micro and nano- electro mechanical systems – sensors, actuators, optical switches, bio-MEMS diodes and nano-wire transistors - data memory lighting and displays, filters (IR blocking)					
Section-B	Quantum Optical Devices: Fuel cells and photo-voltaic cells – electric double layer capacitors – lead-free solder – nano particle coatings for electrical products. Nano catalyst, smart materials, heterogeneous nano structures and composites.					
Section-C	Section-C Nanostructures for Molecular Recognition: Quantum dots, nano rods, nano tubes molecular encapsulation and its applications – nano porous zealots – self-assembled nano reactors - organic electroluminescent displays.					
Section-D	Drug Deliveries: Drug delivery system, nano particle in drug delivery available applications, nanotechnology future application understanding for treatment.					
Course Ou CO1:	itcomes: To acquire t fundamentals	he knowledge of b of nano materials	asic sciences required	l to understand the		
CO2:	To acquire the	e knowledge of electro	onic, optical and magne	tic properties of nano		

materials.

CO3: To get familiarize with the basic concepts of Statistical and Quantum mechanics

Text Books:

- 1. Micro and Nanofabrication, Zheng Cui, Springer 2005.
- 2. Nano structured materials, Jackie Y. Ying, Academic press 2001
- 3. Nanotechnology and nano electronics, W.R, Fahrner, Springer 2005
- 4. Nano engineering of structural, functional and smart materials, Mark J. Schulz, Taylor & Francis 2006.
- 5. Hand book of Nano science, Engineering, and Technology, William A. Goddard, CRC press 2003.
- 6. Nano electronics and Information Technology, Rainer Waser, Wiley-VCH 2003.

- 1. The MEMS Handbook Frank Kreith, CRC press 2002.
- 2. Pradeep T "Nano: The Essentials", McGraw Hill Publishing Co. Ltd., 2007
- 3. Mick Wilson et al, "Nanotechnology", Overseas Press (India) Pvt. Ltd., 2005.
- 4. Charles P. Poole, Jr., Frank J. Owens, "Introduction to nano technology", Wiley, 2003.
- 5. Gunter Schmid, "Nano particles: From Theory to Applications", Wiley VCHV erlag GmbH & Co., 2004.

Name of th	e Course	urse Space Time Wireless Communication				
Course Co	de	PEC-2003	Credits-4	L-3, T-1, P-0		
Total Lectures		52 (1 Hr Each) (L=39, T=13 for each seme		ster)		
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	ssional tests 50%, ttendance 10%)	Max Marks: 50		
		Instruc	tions			
For Paper The questic will consist entire sylla course. Sec and each qu	For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester and examination for the course.					
For Candio Candidates the sections Section E. <i>A</i>	lates: are required to A, B, C & D A non- programi	attempt five questior of the question pap nable calculatoris all	ns in all selecting one qu per and all the subparts owed to use in examinat	uestion from each of of the questions in tions.		
Course Ob To under block co and othe	ojectives: erstand the perfo odes (STBC), A er various space	ormance of MIMO sy ltamonte schemes of time coding schemes	estem, MIMO-OFDM sy channel estimation, spa and their performances	vstem, and space time ce time Trellis codes, analysis.		
Section	on Course Content					
Section-A	<i>Introduction:</i> MIMO wireless communication, MIMO channel and signal model, A fundamental trade-off, MIMO transceiver design, MIMO in wireless networks, MIMO in wireless standards. Equalizer Noise Enhancement, Equalizer Types, Folded Spectrum and ISI- Free Transmission, Linear Equalizers, Zero Forcing (ZF) Equalizers, Minimum Mean Square Error (MMSE) Equalizer, Maximum Likelihood Sequence Estimation, Decision-Eeedback Equalization					
Section-B	Performance Limits Of Multiple-Input Multiple-Output Wire Less Communication Systems: MIMO System Model, Capacity in AWGN, Capacity of Flat-Fading Channels, Channel and System Model, Channel Distribution Information (CDI) Known, Channel Side Information at Receiver, Channel Side Information at Transmitter and Receiver, Capacity of Frequency-Selective Fading MIMO System Capacity Derivation, Capacity of MIMO Systems with Static, Capacity of MIMO Systems with Fading Channels					
Section-C	Static, Capacity of MIMO Systems with Fading Channels <i>Multiple Antennas and Space-Time Communications:</i> Narrowband MIMO Model, Parallel Decomposition of the MIMO Channel MIMO Diversity Gain: Beam forming, Diversity/Multiplexing Tradeoffs, Space-Time Modulation and Coding. ML Detection and Pair wise Error Probability					

	Space-Time Block Codes: Altamonte Space-Time Code with Multiple Receive							
	Constellations STBC for Complex Signal Constellations Decoding of STBC							
	Constellations, SIBC for Complex Signal Constellations, Decoding of SIBC,							
	Completion on Deformance							
	Correlation on Performance							
	Layered Space-Time Codes: LST Transmitters, LST Receivers, QR							
	Decomposition, Interference Minimum Mean Square Error (MMSE)							
	Suppression Combined with Interference Cancellation, Iterative LST Receivers,							
Section-D	VBLAST architecture, DBLAST Architecture.							
Section-D	Space-Time Trellis Codes: Encoder Structure for STTC, Generator Description,							
	And Optimal STTC Based on the Rank, Determinant and Trace Criterion,							
	Performance Comparison for Codes Based on Different Design Criteria, Design							
	of Space-Time Trellis Codes on Fast Fading Channels.							
Course Ou	it comes:							
	the end of the course the students should be able to: Recognize the basic							
	ncents of space time coding techniques and their used in MIMO and MIMO-							
OFDM system								
	valuate the performance of MIMO System in different fading scenario							
CO2: EV	valuate the performance of various space time block codes and space time trallis.							
	des							
	ues.							
CO4: A1	harving the concept of various layered architecture in MINO system.							
Text Book	s:							
1. Larss	on. Erik G. and PetreStoica. Space-Time Block Coding for							
WirelessCommunications, Cambridge University Press(2008).								
2. David, Tse and Viswanath, Pramod, Fundamentals of Wireless								
CommunicationCambridge University Press(2006)								
Com	numerion cumoriage on versity (1655(2000).							
Reference	Books:							
1. Fitzek	, Frank H.P., Katz and Marcos D., Cooperation in Wireless Networks:							

- 1. Fitzek, Frank H.P., Katz and Marcos D., Cooperation in Wireless Networks: Principles and applications, Springer (2007)2nded.
- 2. Arogyaswami,Paulraj, Gore, Dhananjay and Nabar, Rohit., Introduction to Space-Time Wireless Communications, Cambridge, UniversityPress(2008).

Name of th	e Course	Advanced Wireless Networks				
Course Co	de	PEC-2004 Credits-4 L-3, T-1				
Total Lectu	ures	52 (1 Hr Each) (L=	39, T=13 for each seme	ster)		
Semester E Examination	Cnd on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	sional tests 50%, tendance 10%)	Max Marks: 50		
		Instruct	tions			
For Paper	Setters:					
The questic will consist entire sylla course. Sec and each qu	on paper will const of a single quest bus and will car tion A, B, C & I testion will carry	sist of five Sections A, stion with 10-20 subpa- ry 20% of the total n O will have two question 20% of the total marks	, B, C, D & E. Section E arts of short answer type, narks of the semester end ons from the respective so of the semester end exam	will be compulsory, it which will cover the d examination for the ections of the syllabus ination for the course.		
For Candid Candidates the sections Section E. A	lates: are required to a A, B, C & D A non- programmer	attempt five question of the question pap nable calculatoris all	is in all selecting one quere and all the subparts owed to use in examinat	uestion from each of of the questions in tions.		
Course Ob ◆ The obj wireless and perf	 Course Objectives: The objective of this course unit is to study the problematic of service integration in wireless networks focusing on protocol design, wireless network security, implementation and performance issues. 					
Section	Section Course Content					
Section-A	Fundamentals: 4G Networks and Composite Radio Environment, Protocol Boosters, Hybrid 4G Wireless Network Protocols, Green Wireless Networks, Physical Layer and Multiple Access, Multicarrier CDMA, Ultra wide Band Signal, MIMO Channels and Space Time Coding. Introduction to Wireless Networking: Introduction, Difference between wireless and fixed telephone networks, WLAN, Development of wireless networks, 3G and 4G Networks, Traffic routing in wireless networks. Wireless Networking, Packet Processing, Network Speed, Packet Buffering					
Section-B	 Section-B Bluetooth: Overview, Radio specification, Base band specification, Links manager specification, Logical link control and adaptation protocol. Introduction to WLL Technology. Mobile Network: IP packet delivery – Agent advertisement and solicitation – Registration – Tunneling and Encapsulation – Optimizations – Reverse Tunneling – Ipv6., Dynamic Host Configuration protocol, Traditional TCP - Congestion control – Slow start – Fast retransmit/fast recovery – Classical TCP improvements: Indirect TCP – Specific TCP – Mehile TCP 					
Section-C	<i>Mobility and I</i> Distribution,	Resource Manageme Mobility Prediction	ent: Prioritized Handoff in Pico- and Micro	, Cell Residing Time -Cellular Networks,		

	Channel Assignment Schemes, Resource Management in 4G. Mobile Agent-							
	based Resource Management, Joint Data Rate and Power Manageme							
	Dynamic Spectra Sharing in Wireless Networks,							
	Ad Hoc and Sensor Networks: Routing Protocols, Hybrid Routing Protocol,							
	Scalable Routing Strategies, Multipath Routing, Clustering Protocols.							
	Distributed Quos Routing, Sensor Networks Parameters, Sensor Networks							
Section-D	Architecture.							
	Wireless Network Security: IEEE 802.11i Wireless LAN Security, Wireless							
	Application Protocol Overview, Wireless Transport Layer Security, WAP End-							
	to-End Security.							
Course Outcomes:								
CO1:	The students will be able to, Acquire knowledge about Wireless Network							

- Fundamentals. Recognize the various Network Standards and their utility in real world. Acquire knowledge about Routing and Application Layer Protocols.
- **CO2:** Identify wireless network vulnerabilities and apply various security mechanisms to protect networks from security attacks.

Text Books:

- 1. Rappaport, T.S., Wireless Communications, Pearson Education (20072nded).
- 2. Zheng, Jun and Jamalipour, Abbas, Wireless Sensor Networks: A Networking Perspective, Wiley-IEEE Press(2009).

- 1. Tanenbaum, A.S., Computer Networks, 4th Edition, PrenticeHall(2007).
- 2. Stallings, W., Network Security Essentials, Prentice Hall (2017)6thEdition.

Name of th	e Course	Advanced Computer Networks And Protocols				
Course Co	de	PEC-2005 Credits-4		L-3, T-1, P-0		
Total Lectu	ures	52 (1 Hr Each) (L=	39, T=13 for each seme	ster)		
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	ssional tests 50%, ttendance 10%)	Max Marks: 50		
	-	Instruc	tions			
For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the course.						
For Candid Candidates the sections Section E. A	lates: are required to a A, B, C & D A non- program	attempt five question of the question pap nable calculatoris all	ns in all selecting one que per and all the subparts owed to use in examinat	testion from each of of the questions in ions		
Course Ob The obj TCP/IP and to d	 Course Objectives: The objective of this course unit is to study the problematic of service integration in TCP/IP networks focusing on protocol design, implementation and performance issues; and to debate the current trends and leading research in the computer networking area. 					
Section		Cor	urse Content			
Section-A	Review of Network Fundamentals: Network Systems and the Internet, Network Systems Engineering, Packet Processing, Network Speed, A conventional computer system, Fetch-Store paradigm, Network Interface Card functionality, Onboard Address Recognition, Packet Buffering, Promiscuous Mode, IP Datagram, Fragmentation, Reassembly, Forwarding, TCP Splicing. <i>Internetworking:</i> Motivation, Concept, Goals, IP addressing, Address Binding with ARP, IP Datagram, Encapsulation IP Fragmentation and Reassembly, ICMP, TCP, UDP concept and datagram protocols, Remote Login, Introduction to Protocol Specification, Validation and Testing.					
Section-B	<i>Network Standards and Standard Organizations:</i> Proprietary, Open and De- facto Standards, International Network Standard Organizations, Internet Centralization Registration Authorities, Modern hierarchy of registration authority, RFC categories, The Internet Standardization Process.					
Section-C	 authority, RFC categories, The Internet Standardization Process. <i>TCP/IP Network Interface Layer Protocol:</i> TCP/IP Serial Internet Protocols, Point to Point Protocols, PPP core protocols, PPP Feature Protocols, PPP Protocol Frame Formats, ARP and RARP Protocols, IPv4 and IPv6, IP Network Address Translation Protocol, ICMP Protocols and IPv6 Neighbor Discovery Protocol. 					

	Routing and Application Layer Protocols: Communication Protocols,
	Connection Oriented, Connection Less, Working with Network Layer and
Section-D	Transport Layer, Routing Information Protocol (RIP, RIP-2, and Ripping),
	Border Gateway Protocol, User Datagram protocol, SMTP and FTP protocols,
	TFTP Protocols, Hypertext Transfer Protocols.

- **CO1:** The students will be able to acquire knowledge about Network Fundamentals.
- **CO2:** Identify Internetworking.
- **CO3:** Recognize the Network Standards and Standard Organizations.
- **CO4:** Interpret the TCP/IP Network Interface Layer Protocol.
- **CO5:** Acquire knowledge about Routing and Application Layer Protocols.

Text Books:

- 1. Farrel, A., The Internet and Its Protocols A Comparative Approach, Morgan Kaufmann(2004).
- 2. Puzmanová, R., Routing and Switching Time of Convergence, Addison-Wesley(2001).

- 1. Tanenbaum, A.S., Computer Networks, 4th Edition, Prentice Hall(2007).
- 2. Hunt, C., TCP/IP Network Administration, 3rd Edition, O'Reilly Media(2002).
- 3. Keshav, S., An Engineering Approach to Computer Networking, Addison-Wesley(1997).

Name of the Co	urse	Optoelectronics Devices And Circuits				
Course Code		PEC-2006	Credits-4	L-3, T-1, P-0		
Total Lectures		52 (1 Hr Each) (L=39, T=13 for each seme		ter)		
Semester End E	xamination	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Assess	ment: (based	on sessional tests 50%	, Tutorials/Assignments	Max Marks: 50		
	lai 10%, Atten	Instructio	nc			
For Dopor Sotto	R G •	mstructio	115			
The question par	rs: per will consist	of five Sections A B (D & E. Section E will I	he compulsory it will		
consist of a sing	gle question w	ith 10-20 subparts of s	hort answer type, which	will cover the entire		
syllabus and will	carry 20% of	the total marks of the se	mester end examination f	or the course. Section		
A, B, C & D will	have two ques	stions from the respective	e sections of the syllabus a	and each question will		
carry 20% of the	total marks of	the semester end examin	nation for the course.			
For Candidates	:					
Candidates are re	equired to atte	empt five questions in	all selecting one questi	on from each of the		
sections A, B, C	& D of the q	uestion paper and all t	he subparts of the quest	ions in Section E. A		
non- programma	ble calculator	is allowed to use in ex	aminations.			
Course Objectiv	ves:					
✤ The main ob	jective of thi	s course is to underst	tand the physics of opt	oelectronics devices,		
different type	es of photon s	ources and detectors, d	lifferent modulatorselec	trooptic and acousto-		
optic modula	ators, electro	absorption modulator	, basic introduction of	holography, Fourier		
optics and ho	lography and	fiber optic sensors.				
Section		Co	urse Content			
	Review of S	Semiconductor Electr	onics: Overview, Maxy	well's Equations and		
	Boundary C	onditions, Semicondu	ctor Electronics Equati	ons, Generation and		
Section-A	Recombination in Semiconductors, Examples and Applications to					
	Optoelectronic Devices, Semiconductor p-N and n-P Hetero junctions,					
	Semiconduc	tor n-N Hetero junctio	ns and Metal-Semicond	uctor Junctions.		
	Photon Sou	rces and Detectors: S	emiconductor Photon O	ptical Sources, Light		
	Sources and	d Transmitters, Ligh	t Emitting Diodes, E	Burros LEDs, Edge		
	Emitting LEDs, LED Analog Transmission, LED Digital Transmission,					
Section-B	Introduction to Laser, Black Body Radiations, Boltzmann Statistics, Einstein					
	Coefficient	for Absorption and	Emission, Semicond	uctor Laser Diode,		
	Quantum W	ell Laser, Cleaved Cou	upled Cavity (C ³) Laser,	Index Guide Lasers,		
Optoelectronics Integrated Circuits-OEICs.						
	Electro opt	ic and Acousto-opti	c Modulators: Electro	o optic Effects and		
	Amplitude 1	Modulators, Phase Mo	odulator, Kerr Effect a	nd Kerr Modulators,		
	Electro opti	c Effects in Wavegui	de Devices, Scattering	of Light by Sound:		
Section-C	Raman-Nath	1 and Bragg Diffrac	ctions, Coupled-Mode	Analysis for Brag		
	Acousto-opt	ic Wave Coupler.				
	Electro abs	orption Modulator: (Beneral Formulation for	r Optical Absorption		
	Due to an E	lectron- Hole Pair, Fr	anz-Keldysh Effect, Ex	ton Effect, Quantum		

	Confined Stark Effect (QCSE), Inter band Electro absorption Modulator, Self-					
	Electro optic Effect Devices (SEEDs).					
	Fourier Optics and Holography: Introduction to Fourier Transform, Image					
	Forming Properties of Lenses, Holographic Optical Element (HOE), HOE					
	Fabrication Materials, Vibration and Motion Analysis Holographic					
	Techniques, Hologram Interferometer, Stroboscopic Holography, Modulated					
Section D	Beam Holography.					
Section-D	Fiber Optic Sensors: Introduction to Sensors, Fiber Optic Sensor in Healthcare,					
	Fiber Optic Sensor Basic, Angelology, Gastroenterology, Oncology,					
	Neurology, Neurology, Fiber Bragg Grating for Strain and Temperature					
	Sensors, High Temperature Borehole, Seismometer with Fiber Opti					
	Displacement Sensors.					
Course Outco	mes:					
со1: Т	he students will be able to, Identify, formulate and solve different optoelectronics					
d	evices related problems using efficient technical approaches.					
CO2: F	miliarization with the basic physics of optoelectronics devices and interpret					
v	rious optical parameters of the photonic sources and detectors.					
CO3: Perform the coupled-mode analysis for wave coupler and learn about the						
t	pes of effects in electro optic, electro absorption and acousto-optic modulators.					
CO4: R	ealize the concept of new optical technique i.e. Fourier optics and identify the					
n	ost suitable materials for holographic optical element fabrication.					
CO5: L	earn the basics of optical sensors and their applications in medical diagnostics for					
tl	he benefit of public health					

Text Books:

- 1. S. C. Gupta, "Optoelectronic Devices and Systems," Second Edition, PHI Learning Private Limited, New Delhi, 2015.
- 2. Pallab Bhattacharya, "Semiconductor Optoelectronics Devices," Prentice Hall of India Pvt. Ltd., New Delhi, 2006.

- 1. ShunLienChuang,"PhysicsofOptoelectronicDevices,"WileySeriesinPurean
- dAppliedOptics, John Wiley & Sons. Inc., 1995.
 J. Singh, "Opto Electronics-As Introduction to materials and Devices," McGraw-Hill International Edition, 1998.
- 3. B.E.A. Saleh and M.C. Teich, "Fundamental of Photonics, John Wiley and Sons Inc, 2nd Edition,2007.

Name of th	e Course	Artificial Intelligence				
Course Co	de	PEC-2007	Credits-4	L-3, T-1, P-0		
Total Lectu	ures	52 (1 Hr Each) (L=	ster)			
Semester E Examination	Cnd on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	sional tests 50%, tendance 10%)	Max Marks: 50		
		Instruc	tions			
For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the syllabus						
For Candic Candidates the sections Section E. A	lates: are required to a A, B, C & D A non- programm	attempt five question of the question pap nable calculatoris all	is in all selecting one que or and all the subparts owed to use in examinat	testion from each of of the questions in ions.		
 Course Objectives: The objective of this subject is to be familiar with the applicability, strengths, and weaknesses of the basic knowledge representation, problem analyzing, and learning methods in solving particular engineering problems. 						
Section		Сог	urse Content			
Section-A	Fundamental Issues: Overview of AI problems, Examples of successful recent AI applications, Intelligent behavior, The Turing test, Rational versus non- rational reasoning, Problem characteristics: Fully versus partially observable, Single versus multi-agent, Deterministic versus stochastic, Static versus dynamic, Discrete versus continuous, Nature of agents: Autonomous versus semi-autonomous, Reflexive, Goal-based, and Utility- based, Importance of perception and environmental interactions. Philosophical and ethical issues					
Section-B	Basic Search & solving by se Uninformed & deepening), He A*), Space and and local searce Advanced Se Combinatorial annealing, Gen search, Beam & (MDP-solving)	Strategies: Problem is arch, Factored reprisearch (breadth-firse euristics and inform d time efficiency of h methods). arch: Constructing explosion of sea hetic algorithms, Mor search, Minimax Sea and chance nodes.	spaces (states, goals and resentation (factoring s st, depth-first, depth- led search (hill-climbin search, Constraint satist search trees, Dyna rch space, Stochastic nte-Carlo tree search, In arch, Alpha-beta pruning	d operators), Problem state into variables), first with iterative og, generic best-first, faction (backtracking unic search space, search: Simulated mplementation of A* g, Expectimax search		

Section-C	<i>Knowledge Representation:</i> Propositional and predicate logic, Resolution in predicate logic, Question answering, Theorem proving, Semantic networks, Frames and scripts, conceptual graphs, conceptual dependencies. <i>Reasoning under Uncertainty:</i> Review of basic probability, Random variables and probability distributions: Axioms of probability, Probabilistic inference, Bayes' Rule, Conditional Independence, Knowledge representations using Bayesian Networks, Exact inference and its complexity, Randomized sampling (Monte Carlo) methods (e.g. Gibbs sampling), Markov Networks, Relational probability models, Hidden Markov Models, Decision Theory Preferences and utility functions, Maximizing expected utility.	
Section-D	Agents: Definitions of agents, Agent architectures (e.g., reactive, layered cognitive), Agent theory, Rationality, Game Theory Decision-theoretic agents Markov decision processes (MDP), Software agents, Personal assistants, an Information access Collaborative agents, Information- gathering agents Believable agents (synthetic characters, modeling emotions in agents), Learnin agents, Multi-agent systems Collaborating agents, Agent teams, Competitiv agents (e.g., auctions, voting), Swarm systems and Biologically inspired models <i>Expert Systems:</i> Architecture of an expert system, existing expert systems	
	Expert Systems: Architecture of an expert system, existing expert systems: MYCIN, RI. Expert system shells.	
Course Ou	itcomes:	
CO1:	The students will be able to. Analyze the applications of artificial intelligence and categorize various problem domains, uninformed and informed search methods.	
CO2:	Identify advanced search techniques and algorithms like mini max for game playing. Recognize the importance of probability in knowledge representation for reasoning under uncertainty.	
CO3:	Describe Bayesian networks and drawing Hidden Markov Models.	
CO4: Interpret the architecture for intelligent agents and implement an agent.		
Text Books 1. Ricl	: n E., Artificial Intelligence, Tata McGraw Hills (2009)3rded.	
2. Geo Prol	rge F. Luger, Artificial Intelligence: Structures and Strategies for Complex plem Solving, Pearson Education Asia (2009)6thed.	
Reference 1	Books:	
1. Patt 4.Sh (201	erson D.W, Introduction to AI and Expert Systems, McGrawHill (1998), 1sted. hivani Goel, Express Learning- Artificial Intelligence, Pearson Education Asia (3),1sted.	

Name of th	ne Course		Design For IOT			
Course Co	de	PEC-2008	Credits-4	L-3, T-1, P-0		
Total Lectures52 (1 Hr Each) (L=39, T=13 for each			39, T=13 for each seme	ster)		
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.		
Internal	Assessment:	(based on ses	ssional tests 50%,	Max Marks: 50		
Tutorials/A	ssignments 30%,	Quiz/Seminar 10%, At	ttendance 10%)	What What KS: 50		
		Instruc	tions			
For Paper	Setters:					
The question	on paper will con	sist of five Sections A	, B, C, D & E. Section E	will be compulsory, it		
will consist ontire sulle	t of a single ques	stion with 10-20 subparts 20% of the total r	arts of short answer type,	which will cover the		
course Sec	tion $A = C - \delta I$	y 20% of the total h will have two questi	ons from the respective set	ections of the syllabus		
and each ou	lestion will carry	20% of the total marks	of the semester end exam	ination for the course		
For Candio	dates:					
Candidates	are required to	attempt five question	ns in all selecting one of	uestion from each of		
the sections	s A. B. C & D	of the question par	er and all the subparts	of the questions in		
Section E. A	A non- programi	nable calculatoris all	owed to use in examinat	tions.		
Course Of	viactivas:					
Student	s will be able to	understand the conc	ents of Internet of Thin	os (IoT) and can able		
to build	IoT based appli	cations	epts of internet of Thing			
Section		Co	urse Content			
Beetion	Introduction t	o IoT: Defining IoT	C. Characteristics of Io	F. Physical design of		
	IoT, Logical design of IoT, Functional blocks of IoT, Communication models					
	&APIs IoT& M2M: Machine to Machine, Difference between IoT and M2M,					
Section-A	Software define Network Sensors and Actuators modules: Concept, layout,					
	working and applications of different sensors and actuators: temperature sensor,					
	motion sensor LDR sensors, IR sensor, Ultrasonic sensor, Relay etc.					
	Embedded Sy	stems for IoT: Intro	duction to Arduino Pr	ogramming, Arduino		
	interfacing wi	th sensors and act	uators, IoTbased actua	ator operation using		
Section-B	Arduino, Intro	Arduino, Introduction to R-pi and its Programming, R-pi hardware interfacing				
	and applicatio	ns, Smartphone inte	erfacing with R-pi, Wi-F	i module interfacing		
	with R-pi and a	associated applicatio	ns.	-		
	Network and	Communication Pro	tocol: Wireless mediur	n access issues, MAC		
Section C	protocol surv	ey, Constrained Ap	plication Protocol (Co.	AP), Message Queue		
Section-C	Telemetry Tran	sport Protocol (MQT)	Γ), Sensor deployment &	v Node discovery, Data		
	handling and a	nalytics, Cloud platfo	orm for IoTs,.			
	Developing Id	T based Systems:	Experiments with Arc	duino Hardware and		
	sensor interfac	cing procedures. Au	atomatic lighting contr	ol using IoT, home		
Section-D	automation, co	onnected health, sma	rt farming, industry ap	plications, connected		
	vehicles, smar	t city, developing s	ensor based application	n through embedded		
	system platfor	m. Introduction to	Python, Implementing	g IoT concepts with		

	python <i>Challenges in IoT:</i> Design challenges, Development challenges, Security challenges, other challenges.
Course	Outcomes:
CO1:	On successful completion of the course, the student will be able to: Recognize the concepts of Internet of Things.
CO2:	Demonstrate the interfacing of different sensors and actuators modules with embedded systems.
CO3:	Analyze basic protocols in wireless sensor network.
CO4:	Design IoT applications in different domain and be able to analyze their performance.
CO5:	Develop and implement IoT applications using Python.
Text Bo	oks:
1. V	ijay Madisetti, Arshdeep Bahga, "Internet of Things: AHands-On Approach"
2. A	Adrian McEwen, Hakim Cassimally, "Designing the Internet of Things" John Wiley
(2	2014)1 st ed.
D.£	De-In-
Keieren	
1. <u>F</u>	lanes David , Salgueiro Gonzalo, Grossetete Patrick, Barton Rob, Henry
<u>J</u>	erome, ToT Fundamentals: Networking Technologies, Protocols and Use
(ases for the internet of Things", Pearson(2016).
2. V	Valtenegus Dargie, Christian Poellabauer, "Fundamentals of Wireless
S	ensor Networks: Theory and Practice", John Wiley &Sons, Ltd(2011).

Name of th	e Course	Computational Electro magnetic		
Course Co	de	PEC-2009 Credits-4 L-3, T-1, P-0		L-3, T-1, P-0
Total Lectu	ures	52 (1 Hr Each) (L=39, T=13 for each semester)		
Semester E Examinatio	Cnd on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.
Internal Tutorials/A	Assessment: ssignments 30%,	(based on ses Quiz/Seminar 10%, At	sional tests 50%, tendance 10%)	Max Marks: 50
		Instruc	tions	
For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the course.				
For Candid Candidates the sections Section E. A	lates: are required to a A, B, C & D A non- programmer	attempt five question of the question pap nable calculatoris all	is in all selecting one que or and all the subparts owed to use in examinat	uestion from each of of the questions in tions.
 Course Objectives: The objective of course is to develop the skills required to solve problems related to electrostatics, magneto statics, microwaves and optical waves using computational methods. 				
Section	Course Content			
Section-A	Review of Basic Electromagnetic: Electrostatics, Magneto statics, Wave equations, TE, TM and Hybrid modes, Guided wave structures, Metallic waveguides, Dielectric waveguides, Radiating structures Applications of electromagnetic, Historical development of Computational. <i>Numerical Methods:</i> ODE solvers, Euler, Runge-Kutta, Boundary conditions, Propagation of errors. Survey of numerical packages			
Section-B	Finite Difference Time Domain Method: An overview of finite differences time domain method, the 1D, 2D & 3D FDTD algorithm, Obtaining wideband data using the FDTD, Numerical dispersion in FDTD simulations, The PML absorbing boundary condition. Commercial implementations.			
Section-C	ction-C <i>Method Of Moments:</i> (MoM): An overview of Method of Moment (MoM), Thin-wire electrodynamics and the MoM more on basis functions, the method of weighted residuals.			
Section-D	Finite Element Variation land Simplex coord Vector (edge) three- dimension Application: Application t	<i>nt Method</i> (<i>FEM</i>) Galerkin weighted linates, high- frequ elements, Application onal Whitney element Deterministic 3D o two- waveguid	: Introduction of Fin residual formulations: ency variation function on to wave guide Eige t, The time domain FEM application: waveguid e discontinuity probl	ite element method, the Laplace equation, nal, Spurious modes, n value analysis, The A e obstacle analysis, lems, Hybrid finite

	element/method of moment's formulations, an application of the FEM/MoM
	hybrid – GSM base stations.
<u> </u>	

- **CO1:** The students will be able to. Acquire knowledge about history and application computational electromagnetic.
- **CO2:** Acquire knowledge about different computational electromagnetic techniques.
- **CO3:** Solve the electromagnetic problem using computational techniques

Text Books:

- 1. Balanis, C., Antennas, John Wiley and sons (2007)3rdedition.
- 2. David B. Davidson, Computational Electromagnetic for RF and Microwave Engineering, Cambridge University Press2005.

Reference Books:

1. Dennis M. Sullivan, Electromagnetic simulation using the FDTD method

Name of the	Course	se Machine and Deep Learning		
Course Code		PEC-2010	Credits-4	L-3, T-1, P-0
Total Lecture	es	52 (1 Hr Each) (L=39, T=13 for each semester)		
Semester End Examination	d	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.
Internal A	Assessment:	(based on ses	sional tests 50%,	Max Marks: 50
Tutorials/Assi	Tutorials/Assignments 30%, Quiz/Seminar 10%, Attendance 10%)			
Ean Danan Sa	ttong.	Instruc		
The question will consist o	The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the			
entire syllabu	is and will car	ry 20% of the total n	narks of the semester end	d examination for the
course. Sectio	on A, B, C & E) will have two question	ons from the respective se	ections of the syllabus
and each ques	tion will carry .	20% of the total marks	of the semester end exam	ination for the course.
Candidates ar	e required to :	attempt five question	is in all selecting one of	lestion from each of
the sections A	A. B. C & D	of the question pap	er and all the subparts	of the questions in
Section E. A r	non- programm	nable calculatoris all	owed to use in examinat	tions.
Course Obje	ctives.			
↔ To	understand va	rious key paradigms	for machine learning ap	proaches.
* To	familiarize wi	th the mathematical a	and statistical techniques	s used in machine
lear	ming.		1	
 To understand and differentiate among various machine learning techniques. 				
Pro	 Provide technical details about various recent algorithms and software platforms 			
rela	ted to Machin	e Learning with spec	cific focus on Deep Lear	ning.
Section		Cor	urse Content	
I	<i>introduction</i> :	Definitions, Datasets	for Machine Learning,	Different Paradigms
0	of Machine Learning, Data Normalization, Hypothesis Evaluation, VC-			
Section-A	Dimensions an	d Distribution, Bias-	Variance Tradeoff, Reg	ression (Linear)
E	Bayes Decision	n Theory: Bayes deci	sion rule, Minimum erro	or rate classification,
N	Normal density	and discriminate fur	nctions	
	Parameter E	stimation: Maximu	im Likelihood and	Bayesian Parameter
	Estimation. I	Discriminative Me	thous: Distance-based	Experience Former Forme
Section-B L	Jiscriminale F	ion and Dimension	lity Deduction Decision	Forest and Boosting
	RES	ion and Dimension	anty Reduction: PCA,	, LDA, ICA, $S\Gamma\Gamma S$,
	Tusterino k.	means clustering (Gaussian Mixture Mod	eling EM-algorithm
k	Kernel Machir	nes Kernel Tricks	SVMs (primal and dual	l forms) K-SVR K-
Section-C	PCA Artificial	Neural Networks: M	ILP. Backdrop. and RBI	F-Net. Foundations of
	Deep Learning	: DNN, CNN. Auto e	encoders	
Section D I	Deep Network	s: CNN, RNN, LST	M, Attention layers, App	plications (8 lectures)
Section-D 7	Techniques to :	improve deep networ	rks: DNN Optimization,	Regularization, Auto

ML. Representation Learning: U	Jnsupervised	pre-training,	transfer learning	g, and
domain adaptation, distributed re	epresentation,	, discovering	underlying cause	S

The students are expected to have the ability to:

- **CO1:** To formulate a machine learning problem
- **CO2:** Select an appropriate pattern analysis tool for analyzing data in a given feature space.
- **CO3:** Apply pattern recognition and machine learning techniques such as classification and feature selection to practical applications and detect patterns in the data

Text Books:

- 1. Shalev-Shwartz, S., Ben-David, S., (2014), Understanding Machine Learning: From Theory to Algorithms, Cambridge University Press
- 2. R. O. Duda, P. E. Hart, D. G. Stork (2000), Pattern Classification, Wiley-Blackwell, 2nd Edition.
- 3. Goodfellow, I., Bengio., Y., and Courville, A., (2016), Deep Learning, The MIT Press

- 1. Mitchell Tom (1997). Machine Learning, Tata McGraw-Hill
- 2. C. M. BISHOP (2006), Pattern Recognition and Machine Learning, Springer-Verlag New York, 1st Edition.
- 3. Charniak, E. (2019), Introduction to deep learning, The MIT Press.

	le Course	Flexible and 1	Printable Electronics T	Technology
Course Co	de	PEC-2011	Credits-4	L-3, T-1, P-0
Total Lect	ures	52 (1 Hr Each) (L=39, T=13 for each semester)		
Semester I Examinati	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.
Internal Tutorials/A	Internal Assessment: (based on sessional tests 50%, Tutorials/Assignments 30%, Quiz/Seminar 10%, Attendance 10%) Max Marks: 50			
	-	Instruc	tions	
For Paper	Setters:			
The questic will consis entire sylla course. Sec and each qu	The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the course.			
For Candi	dates:			
Candidates the sections Section E. A	are required to s A, B, C & D A non- program	attempt five question of the question pap nable calculatoris all	is in all selecting one que over and all the subparts owed to use in examinat	uestion from each of of the questions in tions.
 Course Objectives: The course will provide an introductory survey of the technology and applications for printed and flexible electronics. Acquire and develop basic concepts and understanding of flexible and printable electronics. Develop an understanding of the relationship between printing techniques, device performance, and target applications for electronics on soft matter. Understand the basic concepts for integration of devices on flexible platforms and the advantages and disadvantages of emerging technology used for future devices. Obtain a fundamental understanding Future Trends of Flexible/Printable electronics technology, and the pathways for commercialization of emerging materials, processes, and tools for printed and flexible electronic systems. 				
Section		Cou	urse Content	
Section-A	Introduction: Introduction to Flexible & Printable electronics- Historical background - Materials, devices, systems, applications - Fabrication techniques - Unique aspects, status in the field and trends, Stretchable electronics, Wearable Electronics, Potential level of printed electronics in the industry, area of applications of printed electronics.			
Section-B	Printing And and roll to r multilayer patt inks, and their electronics, Va	<i>Fabrication Technol</i> oll printing techniq terning, Functional i characterization, diff urious substrates and t	<i>logy</i> : Basics and fundar ues- imprint lithograp nks–Conductive, semi-c ferent materials and their their types.	nentals sheet to sheet hy, spray pyrolysis, conductive, insulating r properties in printed

	Flexible and printable devices: Organic devices on flexible substrate, Sensors	
	and biosensors, RFID, Antenna, FET etc., Examples of flexible physical,	
Section-C	chemical and optical sensors, Actuators, Examples of flexible optical and	
	thermal actuators, Displays, sensor arrays, memory devices, MEMS, lab-on-a-	
	chip, and photovoltaic	
	Future Trends Of Flexible/Printable Electronics Technology: Advanced	
	technologies used in printed electronics production, Energy harvesting and	
	storage components - Energy harvesters - Principles and fundamentals -	
Section-D Examples of flexible energy harvesters - Storage components - F		
	fundamentals, barrier materials, Examples of flexible super-capacitors and	
	batteries, Further processing components - Interconnections, memories,	
	opportunities, obstacles and future trends printed electronics.	
Course Ou	taamaa	

CO1: An ability to apply knowledge of mathematics, science, and engineering

- **CO2:** Ability to design and conduct experiments, as well as to analyze and interpret data.
- **CO3:** An ability to design a system, component, or process to meet desired needs.
- **CO4:** An ability to function on multi-disciplinary teams.
- **CO5:** Ability to identify, formulate, and solve engineering problem

Text Books:

- 1. "Large Area and Flexible Electronics", M. Caironi and Y.Y. Noh, WILEY-VCH, 2015.-"Flexible Electronics: Materials and Applications", W. S. Wong, A. Salleo, Springer, 2009.
- **2.** "Organic and Printed Electronics: Fundamentals and Applications", G. Nisato, D. Lupo, S. Ganz, CRC Press, 2016.
- **3.** "Organic Flexible Electronics: Fundamentals, Devices, and Applications", P. Coseddu and M. Caironi, Elsevier, 2020.
- **4.** ChristophBrabec, UllrichScherf, Vladimir Dyakonov (Editors), Organic Photovoltaics: Materials, Device Physics, and Manufacturing Technologies, Wiley-VCH, 2014.

Reference Books:

- 1. Frederik C. Krebs, Stability and Degradation of Organic and Polymer Solar Cells, Wiley, 2012.
- **2.** Hagen Klauk (Editor), Organic Electronics: Materials, Manufacturing, and Applications, Wiley-VCH, 2006.
- 3. Organic Electronics II: More Materials and Applications, Wiley-VCH, 2012.
- **4.** Franky So (Editor), Organic Electronics: Materials, Processing, Devices and Applications, CRC Press, 2009.
- 5. Mario Pagliaro, Flexible Solar Cells, Wiley-VCH, 2008

Name of the Course

Advanced Antenna Theory and Design

DOCTOR OF PHILOSOPHY IN ELECTRONICS & COMMUNICATION ENGINEERING UIT, HIMACHAL PARDESH UNIVERSITY, SHIMLA

Course Co	de	PEC-2012	Credits-4	L-3, T-1, P-0
Total Lectures		52 (1 Hr Each) (L=	-39, T=13 for each seme	ster)
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.
Internal Tutorials/A	Assessment ssignments 30	t: (based on sea 0%, Quiz/Seminar 10%, A	ssional tests 50%, ttendance 10%)	Max Marks: 50
		Instruc	ctions	
 For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the course. For Candidates: Candidates are required to attempt five questions in all selecting one question from each of the sections A, B, C & D of the question paper and all the subparts of the questions in Section E. A non- programmable calculatoris allowed to use in examinations. 				
 Course Objectives: The course objective is to understand the theory and fundamentals of antenna design. The course helps the students to learn key aspects of practical antenna design. A broad range of antennas such as dipole, loop, micro strip patch, horn, etc are studied during the course. 				
Section	Course Content			
Section-A	<i>Fundamental Concepts:</i> Radiation pattern, near- and far-field regions, reciprocity, directivity and gain, effective aperture, polarization, input impedance, efficiency, Fries transmission equation, radiation integrals and auxiliary potential functions. Radiation from Wires and Loops: Infinitesimal dipole, finite-length dipole, linear elements near conductors, dipoles for mobile communication, small circular loop			
Section-B	Aperture Antennas: Huygens' Principle, radiation from rectangular and circular apertures, design considerations, Babine's principle, and Fourier transform method in aperture antenna theory. Horn and Reflector Antennas: Radiation from sect oral and pyramidal horns, design concepts, prime-focus parabolic reflector and cases grain antennas.			
Section-C	<i>Micro strip Antennas:</i> Basic characteristics, feeding methods, methods of analysis, design of rectangular and circular patch antennas			
Section-D	Antenna A uniform ex arrays usin Woodward	<i>rrays:</i> Analysis of unificitation amplitudes, extignation generation of for the second secon	formly spaced arrays with tension to planar arrays, mial method, Fourier tra	ith uniform and non- synthesis of antenna ansform method, and

- **CO1:** By the end of this course students will have good understanding of antenna fundamentals and the knowhow of designing various kinds of antennas such as dipole, loop, microsotrip patch antennas and arrays.
- CO2: Students will also learn industry standard simulation software Anasys HFSS.

Text Books:

- 1. 1.Balanis, C.A., "Antenna Theory and Design", 3rd Ed., John Wiley & Sons. 2005
- 2. Jordan, E.C. and Balmain, K.G., "Electromagnetic Waves and Radiating Systems", 2nd Ed., Prentice-Hall of India. 1993
- 3. Stutzman, W.L. and Thiele, H.A., "Antenna Theory and Design", 2nd Ed., John Wiley & Sons. 1998

- 1. Elliot, R.S., "Antenna Theory and Design", Revised edition, WileyIEEE Press. 2003
- 2. Garg, R., Bhartia, P., Bahl, I. and Ittipiboon, A., "Microstrip Antenna Design Handbook", Artech House.

Name of th	e Course		Nano-photonics		
Course Co	de	PEC-2013	Credits-4	L-3, T-1, P-0	
Total Lect	ures	52 (1 Hr Each) (L=39, T=13 for each semester)			
Semester E Examination	End on	Max Marks: 100	Min. Pass Marks: 40	Max. Time: 3 Hrs.	
Internal Tutorials/A	Internal Assessment: (based on sessional tests 50%, Tutorials/Assignments 30%, Quiz/Seminar 10%, Attendance 10%) Max Marks: 50				
		Instruct	tions		
For Paper The questic will consist entire sylla course. Sec and each qu	For Paper Setters: The question paper will consist of five Sections A, B, C, D & E. Section E will be compulsory, it will consist of a single question with 10-20 subparts of short answer type, which will cover the entire syllabus and will carry 20% of the total marks of the semester end examination for the course. Section A, B, C & D will have two questions from the respective sections of the syllabus and each question will carry 20% of the total marks of the semester end examination for the course.				
For Candid Candidates the sections Section E. A	lates: are required to A, B, C & D A non- program	attempt five question of the question pap nable calculatoris all	is in all selecting one quere and all the subparts owed to use in examinate	uestion from each of of the questions in tions.	
 Course Objectives: The course is aimed to: Expose them to the emerging area of nano photonic and the phenomena involved in such devices. Provide deep understandings of light – matter interaction at Nano scale. Study different types of nano photonic crystal based devices and systems. 					
Section	Course Content				
Section-A	Review Of Electro Magnetics: Maxwell equations Wave optics Electromagnetic radiations and evanescent waves Quantum mechanics and band theory of solids Particle wave duality Schrodinger equation and electron states Energy bands in solids Optical properties of bulk materials linear optical properties Nonlinear optical effects.				
	 Conventional Photonics: Fresnel Coefficients, Total internal reflection, Evanescent waves, Dielectric waveguides and cavities, Group velocity and density of states. Surface Plasmon Polaritons. Optical properties of noble metals, Nonlocal effects, Surface plasmonpolaritons waveguides, Light focusing.Localized Surface Plasmons. Near-field enhancement and cross section.Simple geometries in the quasi-static limit.Quantum emitters.Purcell effect. 				
Section-B	density of state Nonlocal et focusing.Local section.Simple effect.	es. Surface Plasmon I ffects, Surface ized Surface Plass geometries in the	Polaritons. Optical proper plasmonpolaritons mons. Near-field enha quasi-static limit.Quar	erties of noble metals, waveguides, Light ncement and cross ntum emitters.Purcell	
Section-B Section-C	density of state Nonlocal ef focusing.Local section.Simple effect. <i>Current Topic</i> resolution ima transfer.	es. Surface Plasmon H ffects, Surface ized Surface Plasm geometries in the s On Nano Photonic ging, Plasmonics in	Polaritons. Optical proper plasmonpolaritons mons. Near-field enha quasi-static limit.Quar cs: Photonic Crystals, N 2D materials, Super-pl	erties of noble metals, waveguides, Light ncement and cross ntum emitters.Purcell Ieta materials, Super- anckianradiative heat	

Photonic crystal fibers Photonic Meta materials Electric, magnetic, negative-
index, and chiral Meta materials Applications of optical meta materials

At the end of course student will be able to

- **CO1:** Gain the foundations of nano photonics.
- **CO2:** Understand the mathematical synthesis of Maxwell equations for Photonic systems.
- **CO3:** Acquire the understanding and importance of confinement and propagation.
- **CO4:** Obtain the knowledge of 1-D, 2-D and 3-D Photonic Crystals.
- **CO5:** Gain the design and scope of nano-photonics applications.
- **CO6:** Learn the foundation of plasmonics.

Text Books:

- 1. L. Novotny and B. Hecht, Principles of Nano-Optics. Cambridge University Press, 2nd edition, 2012.
- 2. J. D. Jackson, Classical Electrodynamics. Wiley, 3rd edition, 1999.
- 3. S. A. Maier, Plasmonics: Fundamentals and Applications. Springer, 1st edition, 2007.

- 1. J. D. Joannopoulos, S. G. Johnson.
- 2. J. N. Winn, and R. D. Meade.
- 3. Photonic Crystals: Molding the Flow of Light.
- 4. Princeton University Press, 2nd edition, 2008.